

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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BYW52, BYW53, BYW54, BYW55, BYW56

Vishay Semiconductors

Standard Avalanche Sinterglass Diode



949539

MECHANICAL DATA

Case: SOD-57

Terminals: plated axial leads, solderable per MIL-STD-750,

method 2026

Polarity: color band denotes cathode end

Mounting position: any Weight: approx. 369 mg

FEATURES

- · Controlled avalanche characteristics
- · Glass passivated junction
- · Hermetically sealed package
- Low reverse current
- · High surge current loading
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



HALOGEN

FREE

APPLICATIONS

· Rectification, general purpose

ORDERING INFORMATION (Example)					
DEVICE NAME	ORDERING CODE	TAPED UNITS	MINIMUM ORDER QUANTITY		
BYW56	BYW56-TR	5000 per 10" tape and reel	25 000		
BYW56	BYW56-TAP	5000 per ammopack	25 000		

PARTS TABLE				
PART	TYPE DIFFERENTIATION	PACKAGE		
BYW52	$V_R = 200 \text{ V}; I_{F(AV)} = 2 \text{ A}$	SOD-57		
BYW53	$V_R = 400 \text{ V}; I_{F(AV)} = 2 \text{ A}$	SOD-57		
BYW54	$V_R = 600 \text{ V}; I_{F(AV)} = 2 \text{ A}$	SOD-57		
BYW55	V _R = 800 V; I _{F(AV)} = 2 A	SOD-57		
BYW56	$V_R = 1000 \text{ V}; I_{F(AV)} = 2 \text{ A}$	SOD-57		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT	
		BYW52	$V_R = V_{RRM}$	200	V	
		BYW53	$V_R = V_{RRM}$	400	V	
Reverse voltage = repetitive peak reverse voltage	See electrical characteristics	BYW54	$V_R = V_{RRM}$	600	V	
voltage		BYW55	$V_R = V_{RRM}$	800	V	
		BYW56	$V_R = V_{RRM}$	1000	V	
Peak forward surge current	$t_p = 10 \text{ ms}$, half sine wave		I _{FSM}	50	Α	
Repetitive peak forward current			I _{FRM}	12	Α	
Average forward current	φ = 180 °		I _{F(AV)}	2	Α	
Pulse avalanche peak power	t_p = 20 μ s half sine wave, T_j = 175 °C		PR	1000	W	
Pulse energy in avalanche mode, non repetitive (inductive load switch off)	I _{(BR)R} = 1 A, T _j = 175 °C		E _R	20	mJ	
i ² t-rating			i ² t	8	A ² s	
Junction and storage temperature range			$T_j = T_{stg}$	-55 to +175	°C	

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MAXIMUM THERMAL RESISTANCE (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	R TEST CONDITION SYMBOL		VALUE	UNIT	
Junction ambient	Lead length I = 10 mm, T _L = constant	R_{thJA}	45	K/W	
	On PC board with spacing 25 mm	R_{thJA}	100	K/W	

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 1 A	V _F	-	0.9	1	V
Reverse current	$V_R = V_{RRM}$	I _R	-	0.1	1	μA
neverse current	$V_R = V_{RRM}$, $T_j = 100 ^{\circ}C$	I _R	-	5	10	μA
Breakdown voltage	$I_R = 100 \mu A, t_p/T = 0.01, t_p = 0.3 \text{ ms}$	V _(BR)	-	-	1600	V
Diode capacitance	$V_R = 4 V, f = 1 MHz$	C_D	-	18	-	pF
Reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, i_R = 0.25 \text{ A}$	t _{rr}	-	-	4000	ns
neverse recovery time	$I_F = 1 \text{ A}, \text{ dI/dt} = 5 \text{ A/}\mu\text{s}, V_R = 50 \text{ V}$	t _{rr}	-	-	4000	ns
Reverse recovery charge	I _F = 1 A, dl/dt = 5 A/μs	Q _{rr}	-	=	200	nC

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

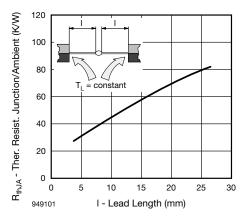


Fig. 1 - Typ. Thermal Resistance vs. Lead Length

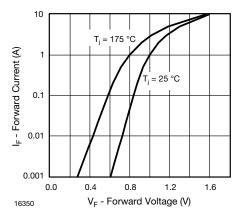


Fig. 2 - Forward Current vs. Forward Voltage

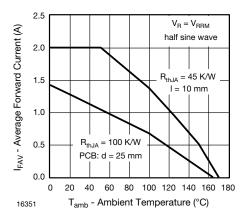


Fig. 3 - Max. Average Forward Current vs.
Ambient Temperature

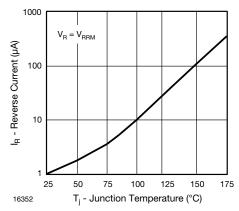


Fig. 4 - Reverse Current vs. Junction Temperature

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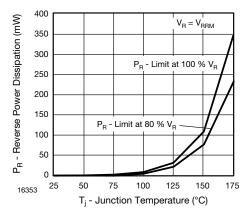


Fig. 5 - Max. Reverse Power Dissipation vs. Junction Temperature

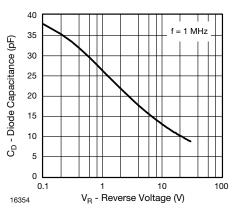


Fig. 6 - Diode Capacitance vs. Reverse Voltage

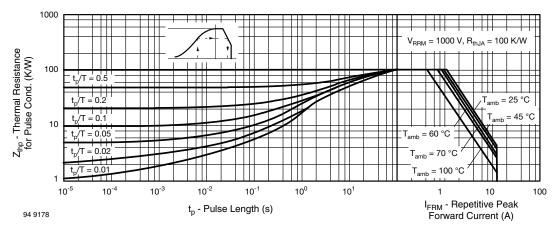
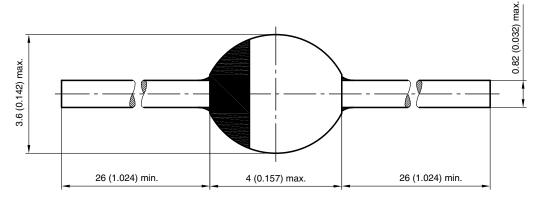


Fig. 7 - Thermal Response

PACKAGE DIMENSIONS in millimeters (inches): SOD-57



20543

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